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# FACSIMILE COVER SHEET

To: Examiner Khiem D. Nguyen

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2

Technology Center 2800

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Facsimile Number: (571) 273-8300

Transmission Date:

April 6, 2006

#### IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant:

Tseng

Docket No.:

TSM03-0763

Serial No:

10/828,884

Art Unit:

2823

Date Filed:

April 21, 2004

Title:

Compensated Linearity Voltage-Control-Capacitor Device by Standard CMOS

**Process** 

### CERTIFICATION OF FACSIMILE TRANSMISSION

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- Election (1 page)

Respectfully submitted,

sty Engeldahl Legal Assistant

Confirmation Respectfully Requested

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Khiem D. Nguyen

For:

Compensated Linearity Voltage-Control-Capacitor Device by Standard

**CMOS Process** 

Mail Stop Amendment Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450

### **ELECTION**

Dear Sir:

In response to the restriction requirement set forth in the Office Action mailed on March 14, 2006, Applicant elects claims 1-19 with traverse for further prosecution in the above patent application. The claims of Group I are directed to a method of forming a semiconductor device, and the claims of Group II are directed to a semiconductor device. Thus, even though Group I is directed to a method and Group II is directed to a device formed by the method, the claims of Group I and Group II are closely related such that examination of both groups would not pose an undue burden on the Examiner.

Respectfully submitted,

<u> (e april 2006</u>

James C. Kestersón Attorney for Applicant

Reg. No. 25,882

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